



PATENT
97-CCP-251 DIV

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)	
ERIC GERRITSEN, et al.)	Group Art Unit: 2813
Serial No.: 09/858,400)	
Confirmation No.: 2138)	Examiner: T. Nguyen
Filed: May 16, 2001)	
For: PROCESS FOR FORMING A LOW)	
RESISTIVITY TITANIUM SILICIDE)	
LAYER ON A SILICON SEMICON-)	
DUCTOR SUBSTRATE (As Amended))	

AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In response to the Office Action dated September 26, 2003, the due date for response to which has been extended to March 26, 2004 by the enclosed petition for extension of time, in connection with the above-identified application, please enter and consider the following amendment and remarks.

04/07/2004 GWORDDF1 00000011 501556 09858400
02 FC:1202 72.00 DA

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to:
Commissioner for Patents, P.O. Box 1450,

Alexandria, VA 22313-1450, on 3/26/04
Date of Deposit

Stephen Bongini
Applicant, Assignee, or Representative

ASB
Signature

3/26/04
Dated